Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.625 inches

Overall Height:

0.190 inches

Overall Width:

0.420 inches

End Application:

4920-01-065-4907

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage and 100.0 repetitive peak off-state voltage

Current Rating Per Characteristic:

8.00 amperes forward current, total rms horsepower metric

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: pnpn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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